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BS170RLRAG

BS170G

ΕN

This Datasheet is presented by the manufacturer

DE

Dieses Datenblatt wird vom Hersteller bereitgestellt

FR

Cette fiche technique est présentée par le fabricant

Small Signal MOSFET 500 mA, 60 Volts

N-Channel TO-92 (TO-226)

Features

• This is a Pb-Free Device*

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Drain – Source Voltage	V_{DS}	60	Vdc
Gate-Source Voltage - Continuous - Non-repetitive (t _p ≤ 50 μs)	V _{GS} V _{GSM}	±20 ±40	Vdc Vpk
Drain Current (Note)	I _D	0.5	Adc
Total Device Dissipation @ T _A = 25°C	P_{D}	350	mW
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

NOTE: The Power Dissipation of the package may result in a lower continuous drain current.

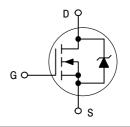


ON Semiconductor®

http://onsemi.com

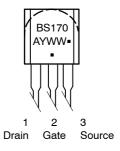
500 mA, 60 Volts $R_{DS(on)} = 5.0 \Omega$

N-Channel





MARKING DIAGRAM & PIN ASSIGNMENT



A = Assembly Location

= Year

WW = Work Week

= Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

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^{*}For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS					
Gate Reverse Current (V _{GS} = 15 Vdc, V _{DS} = 0)	l _{GSS}	-	0.01	10	nAdc
Drain-Source Breakdown Voltage $(V_{GS} = 0, I_D = 100 \mu Adc)$	V _{(BR)DSS}	60	90	-	Vdc
ON CHARACTERISTICS (Note 1)					
Gate Threshold Voltage $(V_{DS} = V_{GS}, I_D = 1.0 \text{ mAdc})$	V _{GS(Th)}	0.8	2.0	3.0	Vdc
Static Drain-Source On Resistance (V _{GS} = 10 Vdc, I _D = 200 mAdc)	r _{DS(on)}	-	1.8	5.0	Ω
Drain Cutoff Current (V _{DS} = 25 Vdc, V _{GS} = 0 Vdc)	I _{D(off)}	-	-	0.5	μΑ
Forward Transconductance ($V_{DS} = 10 \text{ Vdc}$, $I_D = 250 \text{ mAdc}$)	9 _{fs}	-	200	-	mmhos
SMALL-SIGNAL CHARACTERISTICS					
Input Capacitance (V _{DS} = 10 Vdc, V _{GS} = 0, f = 1.0 MHz)	C _{iss}	-	-	60	pF
SWITCHING CHARACTERISTICS					
Turn-On Time (I _D = 0.2 Adc) See Figure 1	t _{on}	-	4.0	10	ns
Turn-Off Time (I _D = 0.2 Adc) See Figure 1	t _{off}	-	4.0	10	ns

^{1.} Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2.0%.

ORDERING INFORMATION

Device	Package	Shipping [†]
BS170G	TO-92 (TO-226) (Pb-Free)	1000 Unit/Tube
BS170RLRAG	TO-92 (TO-226) (Pb-Free)	2000 Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

RESISTIVE SWITCHING

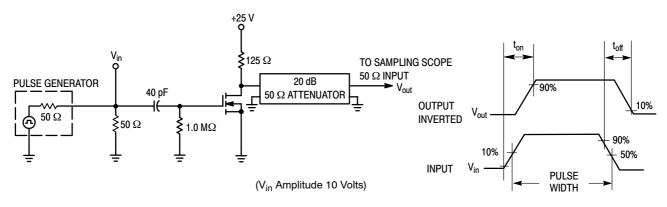


Figure 1. Switching Test Circuit

Figure 2. Switching Waveforms

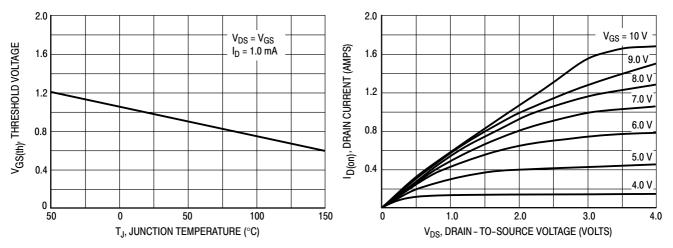


Figure 3. V_{GS(th)} Normalized versus Temperature

Figure 4. On-Region Characteristics

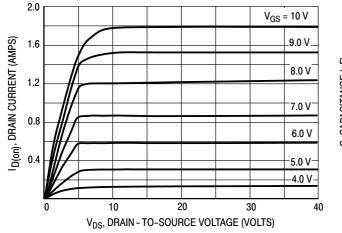


Figure 5. Output Characteristics

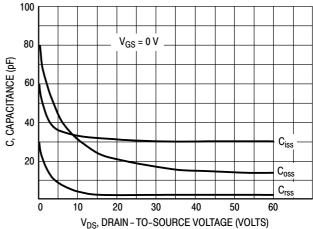
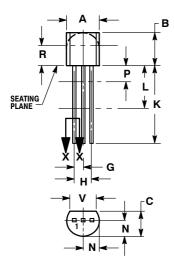


Figure 6. Capacitance versus Drain-To-Source Voltage

PACKAGE DIMENSIONS

TO-92 (TO-226) CASE 29-11 **ISSUE AM**

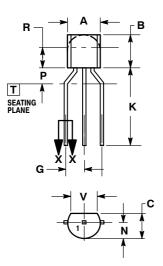


STRAIGHT LEAD **BULK PACK**



- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI
- CONTROLLING DIMENSION: INCH.
 CONTOUR OF PACKAGE BEYOND DIMENSION R
- IS UNCONTROLLED.
 LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.175	0.205	4.45	5.20
В	0.170	0.210	4.32	5.33
С	0.125	0.165	3.18	4.19
D	0.016	0.021	0.407	0.533
G	0.045	0.055	1.15	1.39
Н	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
K	0.500		12.70	
L	0.250		6.35	
N	0.080	0.105	2.04	2.66
P		0.100		2.54
R	0.115		2.93	
V	0 135		3 43	



BENT LEAD TAPE & REEL AMMO PACK



NOTES:

- DIMENSIONING AND TOLERANCING PER
- ASME Y14.5M, 1994.
 CONTROLLING DIMENSION: MILLIMETERS.
 CONTOUR OF PACKAGE BEYOND
 DIMENSION R IS UNCONTROLLED.

MILLIMETEDS

LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

1	MILLIMETERS		
DIM	MIN	MAX	
Α	4.45	5.20	
В	4.32	5.33	
С	3.18	4.19	
D	0.40	0.54	
G	2.40	2.80	
J	0.39	0.50	
K	12.70		
N	2.04	2.66	
P	1.50	4.00	
R	2.93		
٧	3.43		

STYLE 30: PIN 1. DRAIN 2 GATE 3. SOURCE

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